

| L Number | Hits | Search Text | DB | Time stamp |
|-------------|------|--|--|------------------|
| 1 | 6570 | silicide with (titanium platinum) and ((titanium with nitride) TiN) | USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/22 14:36 |
| 2 | 98 | (silicide with (titanium platinum) and ((titanium with nitride) TiN)) and electron with emitter | USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/22 15:05 |
| 3 | 215 | (n-type same epitaxial with silicon) and electron with emitter | USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/22 15:11 |
| 9 | 20 | (n-type same ((silicon with carbide) SiC!) same (phosphorus Nitrogen Vanadium)) and electron with emitter | USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/22 15:36 |
| 10 | 93 | (n-type same ((silicon with carbide) SiC!) same (phosphorus P! Nitrogen N! Vanadium V!)) and electron with emitter | USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/22 15:36 |
| 11 | 187 | (n-type same epitaxial with silicon same (arsenic As! phosphorus P! antimony Sb!)) and electron with emitter | USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/22 15:36 |
| - | 1882 | (313/311,310,346).CCLS. | USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/22 14:33 |
| - | 26 | ((313/311,310,346).CCLS.) and ((porous porosity) with (Silicon Si)) | USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/16 13:30 |
| - | 200 | emit\$5 and ((porous porosity) with (Silicon Si) same n?type) | USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/16 13:50 |
| - | 180 | (emit\$5 and ((porous porosity) with (Silicon Si) same n?type)) and @ad<20010430 | USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/16 13:50 |
| - | 66 | electron with emit\$5 and ((porous porosity) with (Silicon Si) same n?type) | USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/17 08:47 |
| - | 58 | (electron with emit\$5 and ((porous porosity) with (Silicon Si) same n?type)) and @ad<20010430 | USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/16 14:31 |
| - | 59 | field with emit\$5 and ((porous porosity) with (Silicon Si) same n?type) | USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/16 14:31 |

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|--|------|---|---|---------------------|
| | 51 | (field with emit\$5 and ((porous porosity) with (Silicon Si) same n?type)) and @ad<20010430 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/16 14:34 |
| | 4 | (("5652474") or ("5894189")).PN. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/16 14:34 |
| | 66 | (electron with emit\$5) and ((porous porosity) with (Silicon Si) same n\$7?type) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/17 10:20 |
| | 3216 | (313/309,336,351;445/46,50,51).CCLS. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/17 10:20 |
| | 16 | ((313/309,336,351;445/46,50,51).CCLS.) and ((porous porosity) with (Silicon Si) same n\$7?type) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/17 10:21 |
| | 12 | "845845" | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/17 13:57 |
| | 2692 | "n+" with dop\$4 with (Silicon si) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/17 13:58 |
| | 220 | ("n+" with dop\$4 with (Silicon si)) and (("100" with crystal\$) ("110" with crystal\$)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/17 15:11 |
| | 95 | (("n+" with dop\$4 with (Silicon si)) and (("100" with crystal\$) ("110" with crystal\$))) and emit\$5 | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/17 15:19 |
| | 8 | "5990605" | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/18 07:46 |
| | 2 | 5296388.pn. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB | 2003/04/18 07:46 |